

A Compact 1-30 μ H, 1-350 μ F, 5-50m Ω ESR Compliant, 1.5% Accurate 0.6 μ m CMOS Differential $\Sigma\Delta$ Boost DC-DC Converter

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Abstract—Emerging high-end portable electronics demand on-chip integration of high-performance dc-dc power supplies not only to save pin count, printed circuit board (PCB) real estate, and the cost of off-chip components but also to better regulate the point of load (PoL). In the face of a widely variable LC filter, however, integrating the frequency-compensation circuit is difficult without sacrificing stability performance, which is why integrated controller ICs only cater to relatively narrow LC ranges. While $\Sigma\Delta$ control addresses this LC compliance issue in buck dc-dc converters with high equivalent series resistance (ESR) output capacitors, it is not clear how it applies to $\Sigma\Delta$ boost converters. To that end, this paper discusses, analyzes, and experimentally evaluates a prototyped 0.6 μ m CMOS differential $\Sigma\Delta$ boost converter. Experimental results verified the switching supply was stable across 1-30 μ H, 1-350 μ F, and 5-50m Ω of inductance, capacitance, and ESR while keeping output voltage variations in response to 0.1-0.8A load and 2.7-4.2V line changes to less than $\pm 1.5\%$, peak efficiency at 95%, and switching frequency variation to less than 27%.

Index Terms—differential $\Sigma\Delta$ control, boost dc-dc converter

I. INTRODUCTION

INTEGRATING dc-dc power supplies on chip reduces pin count, printed circuit board (PCB) space, off-chip components, design complexity, and time to market, in other words, cost and form factor. The frequency-compensation circuit, however, is difficult to integrate without limiting the LC filter range for which the converter is stable [1]. This design constraint is severe in converters targeted for a wide application space where nominal off-chip LC values already span a substantial range without the widening effects of process tolerance and operating temperatures. Even in niche applications where the LC filter is on chip or in package, compact multiple input-output converters often change topology and LC filter combination dynamically to accommodate a diverse loading environment, changing the LC values for which the converter is to remain stable [2].

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Buck dc-dc converters implementing $\Sigma\Delta$ control [3-6] often enjoy wide LC compliance but only when the output capacitor has sufficient equivalent series resistance (ESR) for its voltage to overwhelm that of the intrinsic capacitor. As a result, the ESR voltage mostly sets the terminal voltage of the capacitor, impressing the inductor ripple current information on the output voltage and achieving current-mode-like control. Reported literature on boost $\Sigma\Delta$ converters, on the other hand, focuses on fixed LC filter applications [7-8], largely circumventing and therefore ignoring wide LC variations.

In addition to LC compliance, steady-state accuracy demands high-frequency operation [8], which in on-chip converters, translates to considerable noise content, especially when subjected to relatively high load currents. Despite the well-known advantages of differential-mode circuits in rejecting noise, the added circuit complexity, silicon real estate, and power demands over their single-ended counterparts often prohibit their effective use. As a result, $\Sigma\Delta$ controllers in literature are single-ended structures limited to lower switching frequencies or lower output power capabilities.

This paper discusses, intuitively analyzes, and experimentally evaluates the design of a 0.6 μ m CMOS differential $\Sigma\Delta$ boost switching supply aimed at extending LC filter compliance and increasing on-chip noise immunity. After a discussion on the operation of $\Sigma\Delta$ controllers and their system-level design implications in Section II, Section III introduces and discusses the system architecture and IC design details of the proposed strategy. Section IV then presents and evaluates the experimental results obtained and Section V draws relevant conclusions.

II. $\Sigma\Delta$ CONTROL IN BOOST CONVERTERS

A. Circuit

Unlike buck converters, the inductor current ripple in boost converters (Fig. 1) does not completely flow to the output capacitor. This is because during the on time of switch MN, the inductor is disconnected from the output by reverse-biased diode D. Because the output voltage does not reflect the behavior of the inductor current, as in buck converters with non-negligible ESRs, $\Sigma\Delta$ control in boost converters cannot rely on output voltage alone. Instead, the inductor current must

also be sensed and mixed with the output voltage in the negative feedback loop to achieve current-mode-like control characteristics. A hysteretic comparator then modulates the frequency and duty cycle of switch MN based on how the scaled sum (v_{SUM}) of the ripples (scaled by $g_{mi}R_S$ and $g_{mv}R_S$) compares against a user-defined hysteresis window. While the output voltage is compared to an independent dc reference, the inductor current, whose dc value changes with load, is self-referenced against its own average value.

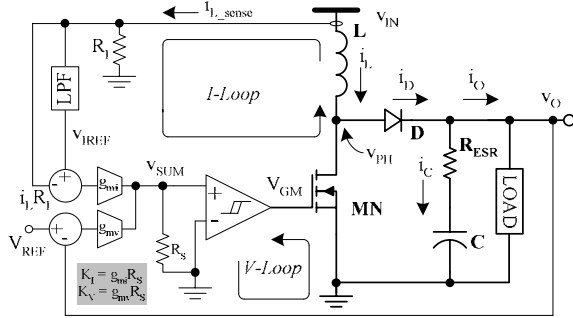


Fig. 1. Simplified schematic of current and voltage mixing in a $\Sigma\Delta$ boost converter.

B. Controller Design Requirements

1) *Stability*: The variation of the poles and zeros that depend on the output filter limits the $R_{ESR}LC$ space for which the $\Sigma\Delta$ controller is stable. To be more specific, LC values in a boost converter produce (Uncompensated LG_V in Fig. 2(b)) a pair of complex-conjugate poles (p_{LC}) and a right half-plane (RHP) zero (z_{RHP}) and the capacitor and its ESR a left half-plane zero (z_{ESR}). The latter typically does not reside within frequencies of interest intentionally because larger ESR values increase the output ripple voltage [9]. While an increase in the on time of switch MN increases the energy stored in the inductor and subsequently the output voltage, disconnecting the output to do so allows the output voltage to droop, opposing the ultimate effect of increasing MN's on time. This opposing effect

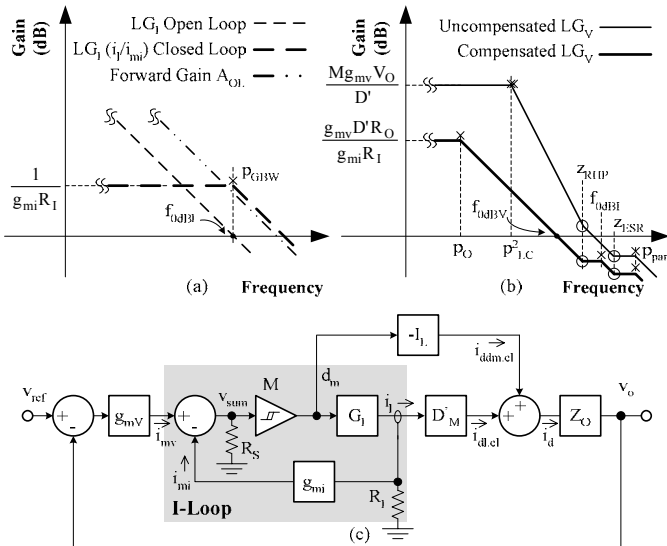


Fig. 2. High frequency Bode magnitude plots of the (a) current and (b) voltage loops in a $\Sigma\Delta$ boost converter, and (c) equivalent control diagram highlighting the current loop, an inner closed-loop gain for the overall voltage loop.

amounts to an out-of-phase, feed-forward path in the voltage loop from the gate of switch MN to the output (z_{RHP}).

The current loop is actually an inner loop for the voltage loop (Fig. 2(c)). As such, the current loop must first be stable and its closed-loop form used to determine the stability conditions of the voltage loop. One peculiarity of the boost converter is that the outer loop extracts two signals from the inner loop, as the diode current is the product of inductor current i_L and off duty cycle d_M' , which is a signal-flow way of describing z_{RHP} and why Fig. 2(c) extracts two feed-forward closed-loop signals (e.g., $i_{ddm,cl}$ and $i_{dl,cl}$) to output v_O .

The gain across the current loop is the product of the gains across the low-pass filter (LPF) and accompanying $R_I g_{mi} R_S$ combination, modulator gain M , and switch-inductor MN-L combination. Under dc conditions, the sensed inductor current $i_L R_I$ equals its self-reference v_{REF} , giving a zero at the origin because the difference between the two is zero, but the difference increases with frequency as the output v_{REF} of the LPF is shunted to ground. Beyond the filter pole p_{LPF} , however, v_{REF} has negligible ac signals and the loop gain levels.

The small-signal gain across switch-inductor MN-L (G_I) is the ratio of small-signal inductor current i_L and duty cycle d_m , which results from applying dc output voltage V_O (variations in v_O are negligible at high-frequency) across inductor impedance Ls during the fraction of time MN is off (off duty cycle d_M' or $1-d_M$ or its small-signal equivalent $-d_m$):

$$G_I \Big|_{f > p_{LC}^2} \equiv \frac{i_L}{d_m} = \frac{V_{IN} - v_{ph}}{Ls \cdot d_m} = \frac{0 - (-d_m V_O)}{Ls \cdot d_m} = \frac{V_O}{Ls}, \quad (1)$$

where the lower-case and capital subscripts indicate ac and dc quantities, respectively. Thus, the current loop gain $|LG_I|$ at frequencies past LPF p_{LPF} (and LC poles p_{LC}^2) is:

$$|LG_I|_{f > p_{LPF}} = \left(\frac{v_{sum}}{i_L} \right) \left(\frac{d_m}{v_{sum}} \right) \left(\frac{i_L}{d_m} \right) = (R_I g_{mi} R_S) M \left(\frac{V_O}{Ls} \right). \quad (2)$$

Hence, at high frequencies, LG_I has a single pole response (Fig. 2(a)) and is therefore stable. Its unity-gain frequency (f_{0dBI}) largely sets the switching frequency of MN at

$$f_{0dBI} = \frac{R_I g_{mi} R_S M V_O}{2\pi L}. \quad (3)$$

The compensated loop gain of the voltage loop ($|LG_V|$) is the product (Fig. 2(c)) of the gains across transconductor g_{mv} , the closed-loop current gain $A_{I,CL}$ of the current loop from i_{mv} to diode current i_d , and the load impedance Z_O . The latter is a parallel combination of output capacitive impedance $1/sC_O$ and output resistance R_O . Diode current i_d is the product of i_L and d_M' so its linearized small-signal counterpart varies with both i_L and i_{dm} :

$$i_d = i_L \left(\frac{\partial i_d}{\partial i_L} \right) + d_m \left(\frac{\partial i_d}{\partial d_m} \right) = i_L D_M' - d_m I_L, \quad (4)$$

where D_M' and I_L are the dc off duty cycle ($1-D_M$) and inductor current, respectively, the latter of which is equivalent to I_O/D_M' or $I_O/(1-D_M)$. Note the feed-forward component is $d_m I_L$, which is out of phase with i_L (Fig. 2(c)).

Because two current-loop current components $i_L D_M'$ and $d_m I_L$

are fed to Z_O (Fig. 2(c)), closed-loop current gain $A_{I,CL}$ (from i_{mv} to i_d) is comprised of the closed-loop gain to i_1 and d_m and their translation to i_d :

$$A_{I,CL}|_{f \gg p_{LPF}} = \left(\frac{i_1}{i_{mv}} \right)_{CL} D_M' - \left(\frac{d_m}{i_{mv}} \right)_{CL} I_L = \left(\frac{i_1}{i_{mi}} \right)_{CL} \left(D_M' - \frac{LsI_L}{V_O} \right), \quad (5)$$

where

$$\left(\frac{i_1}{i_{mi}} \right)_{CL} = \frac{A_{OL}}{1 + |LG_I|} = \frac{R_S M \left(\frac{V_{OUT}}{Ls} \right)}{1 + R_I g_{mi} R_S M \left(\frac{V_O}{Ls} \right)} \approx \frac{1}{R_I g_{mi}} \quad (6)$$

where A_{OL} is the forward gain from i_{mi} to i_1 and a RHP zero results in equation (5) when feed-forward component LsI_L/V_O just exceeds D_M' , which happens at $D_M' V_O / 2\pi L I_L$ (z_{RHP}).

The compensated voltage loop gain ($|LG_V|$) is therefore

$$|LG_V|_{f \gg p_{LPF}} = g_{mv} A_{I,CL}|_{f \gg p_{LPF}} \left(R_O \parallel \frac{1}{sC_O} \right) \approx g_{mv} \frac{D_M' - \frac{LsI_L}{V_O}}{R_I g_{mi}} \left(R_O \parallel \frac{1}{sC_O} \right) \Big|_{f > p_O} \approx \frac{g_{mv} \left(D_M' - \frac{LsI_L}{V_O} \right)}{R_I g_{mi} s C_O}, \quad (7)$$

where the loop has a single pole at p_O or $1/2\pi R_O C_O$, z_{RHP} remains, and its unity-gain frequency is at

$$f_{0dBV} \approx \frac{g_{mv} D_M'}{2\pi R_I g_{mi} C_O}. \quad (8)$$

Assuming that the pole introduced by the current loop at f_{0dBI} is well beyond f_{0dBV} , z_{RHP} needs to be above f_{0dBV} giving the first stability condition for the system:

$$z_{RHP} = \frac{D_M' V_O}{2\pi L I_L} > f_{0dBV} \approx \frac{g_{mv} D_M'}{2\pi R_I g_{mi} C_O} \quad (9)$$

$$\text{or} \quad \frac{L I_L}{V_O C_O} = \frac{L I_O}{C_O V_O D_M'} < \frac{R_I g_{mi}}{g_{mv}}. \quad (10)$$

Consequently, for the closed-current-loop expression used ($1/R_I g_{mi}$) to remain valid through f_{0dBV} , the unity-gain frequency of the current loop (f_{0dBI}) must well exceed f_{0dBV} , providing the second stability condition:

$$f_{0dBI} \approx \frac{R_I g_{mi} R_S M V_O}{2\pi L} \gg f_{0dBV} \approx \frac{g_{mv} D_M'}{2\pi R_I g_{mi} C_O}. \quad (11)$$

The linearized modulator gain M can be estimated by recognizing that the converter switching frequency in this self-oscillating $\Sigma\Delta$ controller corresponds to f_{0dBI} when inequality (11) is satisfied or in other words, the current-ripple dominates in v_{SUM} . Then, the switching frequency given by

$$f_{sw} = \frac{g_{mi} R_S R_I}{\frac{V_H}{|di/dt|_{on}} + \frac{V_H}{|di/dt|_{off}}} = \frac{g_{mi} R_S R_I}{L} \frac{V_{IN}(V_O - V_{IN})}{V_O V_H}, \quad (12)$$

where V_H is the width of the comparator hysteresis window, is equated to f_{0dBI} to give

$$M \propto \frac{V_{IN}(V_O - V_{IN})}{V_O^2 \cdot V_H} = \frac{D_M D_M'}{V_H}. \quad (13)$$

The last stability condition is for the LPF pole p_{LPF} to remain low enough to ensure LG_I exceeds unity below the RHP zero

thereby closing the current loop and masking the effects of said zero. This low frequency LPF pole, because it slows the response time of the effective inductor current reference (v_{REF}) and therefore its ability to converge on the average output load current (I_O), delays the response of the system and degrades transient response [10].

2) *Steady-State Error and Ripple*: When including the effects of switching and propagation delays, the sum (v_{SUM}) of the current and voltage ripples extends beyond the limits established by the hysteretic window of the comparator (Fig. 1). For switch duty-cycles away from the symmetrical 50% value, the asymmetry in the rising and falling slopes of v_{SUM} results in unequal positive and negative excursions of v_{SUM} beyond the hysteresis window. This inequality introduces an error in the average value of v_{SUM} and therefore the output voltage, depending upon the switching delay t_d and the magnitude and asymmetry (duty-cycle) of the v_{SUM} ripple slopes. Assuming that g_{mi} is significantly greater than g_{mv} at the switching frequency, [11] shows that this steady-state error is

$$V_{err} = V_{REF} - V_O = \left(\frac{g_{mi_fsw}}{g_{mv_dc}} \right) \left(\frac{t_d}{2L} \right) (V_O - 2V_{IN}), \quad (14)$$

where g_{mi_fsw} and g_{mv_dc} are values of g_{mi} and g_{mv} at the switching frequency and dc respectively. Equation (14) suggests a small switching-frequency value of g_{mi} and a large dc value of g_{mv} for low steady-state error. The error is the worst at the smallest inductor value in a variable LC environment. The switching ripple is inversely dependent on the output capacitance and switching frequency, which, for a well-designed converter, is approximately equal to f_{0dBI} .

3) *Switching Frequency Variations*: As stated earlier, the switching frequency of the system (f_{sw}) is set by the unity-gain frequency of the current loop f_{0dBI} , which is directly proportional to V_O and gain constant $R_I g_{mi} R_S M$, and inversely proportional to L . Other parameters remaining constant, the switching frequency therefore depends on M showing a parabolic variation that peaks when D_M and D_M' are equal at 50% duty-cycle. From a time-domain perspective, however, the minimum propagation delay across comparator M and other switching delays set the maximum switching frequency of the system. As a result, arbitrarily increasing gain $R_I g_{mi}$ to keep f_{0dBV} below z_{RHP} and therefore increase LC compliance increases f_{sw} (f_{0dBI}) beyond the capabilities of M . In terms of proportionality (13), loops delays lead to excursions of the regulated v_{SUM} ripple beyond the constraints set by the comparator hysteresis, thus increasing the effective hysteresis window, decreasing M and hence f_{0dBI} (switching frequency).

III. DESIGN

A. System Design

The main feature of the foregoing design is LC compliance and key design parameters for stability, regulation, and frequency performance are voltage and current gains g_{mv} and $R_I g_{mi}$. The primary objectives of the proposed design are for

g_{mv} to exceed $R_I g_{mi}$ at low frequencies to reduce steady-state dc errors in v_O and $R_I g_{mi}$ to exceed g_{mv} at moderate-to-high frequencies to shift f_{0dBI} (f_{sw}) above f_{0dBV} and in the process turn i_L into a current source in the voltage loop masking the effects of the LC complex-conjugate pole pair and RHP zero. Another design goal is to make g_{mi} inversely proportional to frequency below and near f_{0dBI} (f_{sw}) by means of pole p_1 (Fig. 3) to compensate partially for switching frequency variations, without resorting to additional frequency-regulating loops. The pole p_1 that constitutes a second pole in the current loop in addition to that in G_I , is compensated by the zero z_1 . Fig. 3 illustrates the proposed frequency-dependent current and voltage gains g_{mi} and g_{mv} , Table 1 describes the operating conditions and design parameters of the targeted 2.7-4.2V Li-Ion powered, 5V-0.8A output supply.

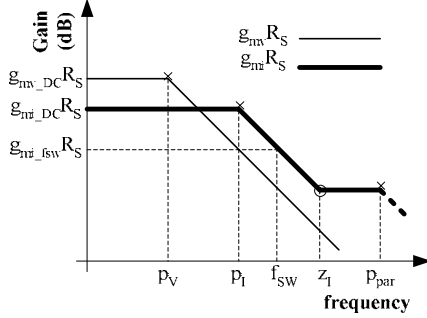


Fig. 3. Frequency-dependent voltage and current gains g_{mv} and g_{mi} .

Table 1. System design parameters.

Parameter	Value	Parameter	Value
V_{IN}	2.7–4.2V	V_O	5V \pm 5%
C	15–350 μ F	L	1–30 μ H
$g_{mv_dc} R_S$	40V/V	p_v	7.5kHz
$g_{mi_dc} R_S R_I$	8V/A	$g_{mi_hr} R_S R_I$	1.6V/A
p_1	160kHz	z_1	800kHz
p_{par}	10MHz	I_{OUT}	0–0.8A

Since the feedback in the proposed $\Sigma\Delta$ controller includes high-bandwidth signals with harmonic components exceeding the switching frequency, the circuit must be tolerant to switching (supply and ground) noise, which is why a differential controller is proposed (Fig. 4). Inductor current, sensed through sense-resistor R_I , is amplified by amplifier A_{DI} whose differential output is internally low-pass filtered through an RC filter to generate a second output, viz., self-referenced signal v_{REF} . The ripple in the sensed output voltage is

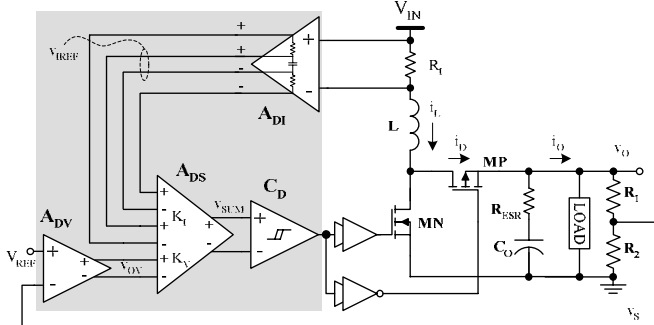


Fig. 4. System schematic of the designed $\Sigma\Delta$ boost converter.

amplified by A_{DV} , which also introduces pole p_v in the voltage path. The outputs of amplifiers A_{DI} and A_{DV} are then mixed by summing amplifier A_{DS} whose output is ultimately modulated into the duty-cycle of switches MN and MP by hysteretic comparator C_D . In this IC prototype, the switches and their gate drivers are off-chip, along with the LC filter elements.

B. IC Design

State-of-the-art $\Sigma\Delta$ controllers [3] employ high loop-gain, op-amp based, closed-loop amplifiers to accurately scale the gains of the sensed variables. Besides being susceptible to supply and ground noise, given their signals are single-ended, the switching frequency is limited by the speed of the controller, which is in turn set by the op amp's bandwidth. Current-mode processing based on current-conveyors [8] improves the bandwidth by reducing the number of high-impedance nodes and their associated voltage swings, but their vulnerability to noise, although somewhat improved, is still limited to the capabilities of single-ended processing schemes.

The presented controller implements a simple differential circuit where the feedback loop is closed around a single transistor and its source degenerating resistor, thereby allowing high bandwidth operation. In addition, the complexity associated an output common-mode feedback circuit is eliminated. The proposed system, designed in a 0.6 μ double-poly, CMOS process with poly-poly capacitor (1fF/ μ^2) and high-resistance poly (1k Ω/\square) options, also shows that the open-loop gain can be reduced to achieve high bandwidth without incurring a significant tradeoff in accuracy.

1) Basic Amplifier Implementation

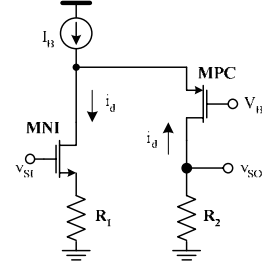


Fig. 5. Basic amplifier block in designed circuit.

The source-degenerated input transistor MNI produces an ac drain current i_d that is folded through cascode PMOS transistor MPC to the output resistor R_2 , generating the amplified output voltage v_o . The ac gain of this circuit is

$$A = \frac{v_{so}}{v_{si}} = \frac{R_2}{R_1} \left(\frac{g_m R_1}{1 + g_m R_1} \right) \equiv \frac{R_2}{R_1} (K), \quad (15)$$

where g_m is the transconductance of MNI. Since the ratio R_2/R_1 can be designed with very high accuracy ($< 0.5\%$) the net accuracy of A across process and temperature variations is determined through the sensitivity of K to small, and in the worst case, uncorrelated variations in the g_m and R_1 :

$$K + \Delta K = \frac{(g_m + \Delta g_m)(R_1 + \Delta R_1)}{1 + (g_m + \Delta g_m)(R_1 + \Delta R_1)} \approx K + \frac{\Delta g_m R_1 + \Delta R_1 g_m}{(1 + g_m R_1)^2}, \quad (16)$$

where Δg_m and ΔR_1 are small variations in g_m and R_1 respectively, and second order terms are ignored. Therefore

the relative sensitivity of K is

$$\frac{\Delta K}{K} \approx \frac{1}{1 + g_m R_1} \left(\frac{\Delta g_m}{g_m} + \frac{\Delta R_1}{R_1} \right). \quad (17)$$

Equation (17) confirms that the term $g_m R_1$, which is the open loop gain of the source-degenerating MNI- R_1 series feedback loop, suppresses the variations in i_d from those in its determining terms g_m and R_1 . As a result, by appropriately increasing the value of $g_m R_1$, a desired accuracy specification for gain A (e.g., $\pm 10\%$), can be met. In the limit, when the loop gain $g_m R_1$ is much greater than unity, K tends to a constant value of unity and $A \approx R_2/R_1$.

The MNI- R_1 loop that determines i_d , has high bandwidth limited only by the product of R_1 and the parasitic diffusion capacitance at the source of MNI. The pole at the other relatively high-resistance node i.e., the output node, is also at a high frequency because the cascode transistor MPC is designed with almost the minimum drawn length, keeping its drain capacitance small. Overall, a high-bandwidth amplifier can be achieved with a desired level of accuracy. The following sub-sections describe adaptations of the aforementioned circuit to the controller blocks shown in Fig. 4.

2) Current-Sense Amplifier (A_{DI})

The amplifier circuit (Fig. 6) implements a fully differential version of the basic cell in Fig. 5. Accordingly, the effective source-degenerated transconductor MNI+ R_1 from Fig. 5 is replaced by a matched differential transconductor (G_R) composed of MN11-12+ R_{11-12} , where the common node v_C is ac-ground. The amplified differential voltage across the resistors R_{21-22} is buffered by the source-follower stages MP31-32, to give the primary differential output v_{IL} . A differential RC filter yields the low-frequency component (v_{ILREF}) of v_{IL} as the sensed current reference. In actuality, the capacitors in the RC filter are implemented using voltage-mode capacitor multipliers [12] to save area. The output common-mode level is naturally set by the DC current flowing through resistors R_{21-22} , and the source-gate voltages of buffer transistors MP31-32, both component pairs being carefully laid out to minimize offsets. As for the other following blocks, the DC gain of current-sense amplifier is designed for an accuracy of $\pm 10\%$ over worst-case PVT corners by appropriate choice of input devices MN11-12 and resistors R_{11-12} .

C. Voltage-Sense Amplifier (A_{DV})

One of the drawbacks of the circuit in Fig. 6 is that the input

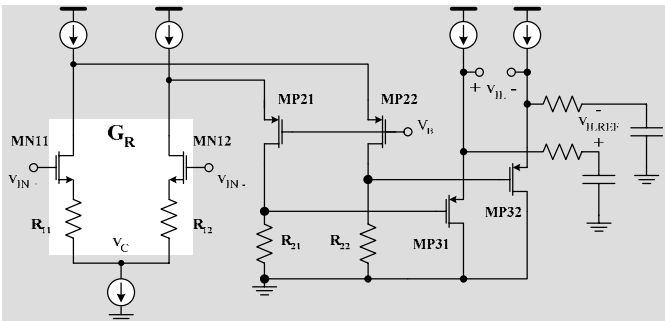


Fig. 6. Simplified circuit schematic for the current-sense amplifier.

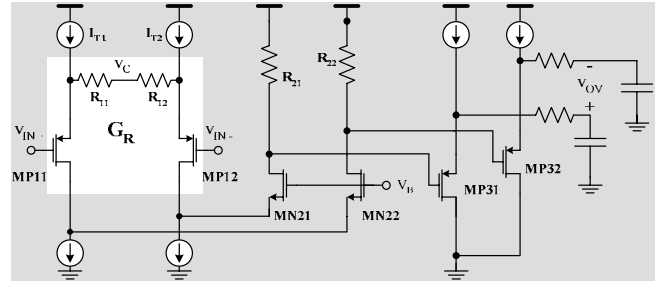


Fig. 7. Simplified circuit schematic for the voltage-sense amplifier.

common-mode range (ICMR) is reduced by the additional DC voltage drop across the source-degenerating resistors R_{11-12} . While this is not a concern for the current-sense amplifier whose input common-mode level is close to V_{DD} , it poses a problem for the voltage-sense amplifier whose common-mode input is at the reference voltage (~ 1.2 V). To improve the ICMR, the tail current is split into two sources I_{T1} - I_{T2} (Fig. 7) each half of the original value and the source-degenerating resistors are relocated so that they do not carry any DC current. The transistor DC biasing currents and the ac equivalent circuit are unchanged with node v_C being ac ground; hence, resistors R_{11-12} provide identical series feedback as described for Fig. 5 giving similar amplification.

The expected repercussion of splitting the tail current is an increased possibility of mismatch and therefore, a higher input-referred offset voltage; however, it can still be kept small by careful design and layout. Apart from this change in the input stage, the rest of the amplifier design is essentially the same as in Fig. 6, with changed polarities of the input and cascode transistors to meet input common-mode requirements. An RC filter at the amplifier output introduces the desired pole p_V (Fig. 3) in voltage path. As before, the physical filter capacitors are reduced in size by capacitor multipliers.

3) Summing Amplifier (A_{DS})

The summing amplifier is readily realized by combining the output currents of multiple differential transconductors (Fig. 8(a)) based on the circuit in Fig. 5. Consequently, in the circuit implementation (Fig. 8(b)) each summed input corresponds to a differential pair that feeds its output ac current to a common pair of cascode (common-gate) transistors MP21-22. The differential output voltage v_{SUM} across resistors R_{21-22} , by superposition, is

$$v_{SUM} = (i_v + i_{i1} + i_{i2}) Z_S = (G_{RV} v_v + G_{R1} v_{i1} + G_{R2} v_{i2}) Z_S, \quad (18)$$

where the $G_{RV, 1}$ are the differential transconductances, v_v, i_{i1}, i_{i2} and i_v, i_{i1}, i_{i2} are the input voltage and output current contributions from each input differential pair, and Z_S is the differential impedance looking into the output given by

$$Z_S \approx 2R_{21} \parallel \left(2R_{23} + \frac{1}{C_2} \right), \quad (19)$$

ignoring the impedance looking into the drains of the cascode transistors MP21, 22. The gain from each input to the output is designed by choosing the appropriate source degenerating resistor value based on the earlier analysis for Fig. 5.

The inputs to each differential pair are chosen to have the same common-mode value under steady state conditions to

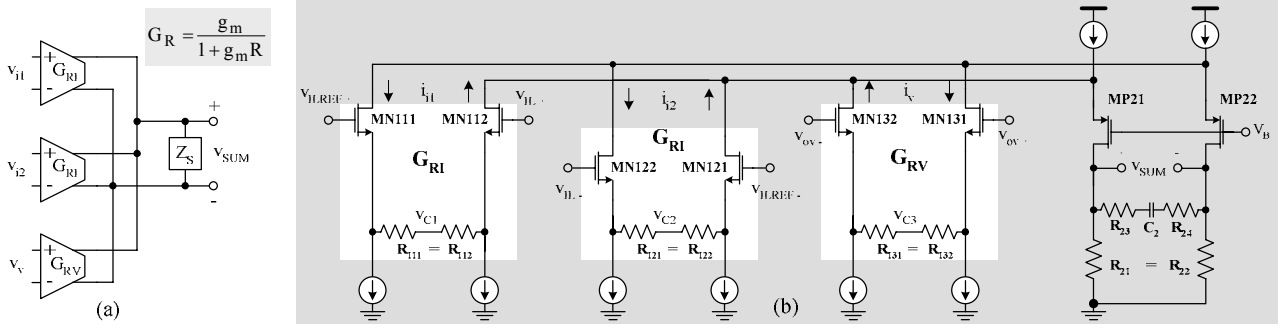


Fig. 8. Simplified (a) block diagram and (b) circuit schematic for the summing amplifier.

reduce body-effect related mismatch. In the actual circuit, the summed output v_{SUM} is followed by source follower buffers, but these are omitted for simplicity from Fig. 8(b). The resistors R_{23-24} and capacitor C_2 at the output introduce the pole-zero pair p_{I-Z1} from Fig. 3.

D. Comparator (C_D)

The comparator design is standard with a preamplifier and latch for optimal propagation delay ($<25ns$) [13]. As such, the circuit is not included here for brevity. The interested reader is encouraged to consult literature for details [13], [14].

IV. EXPERIMENTAL RESULTS

In order to validate the functionality of the circuit blocks as well as the controller system, the prototype IC (in DIP40 package) is designed in two parts –

A. a set of circuit blocks that are not interconnected on-chip have all their I/O terminals accessible via package pins, and,

B. an additional set of identical circuit blocks are interconnected on-chip as in Fig. 4 with the only inputs of amplifiers A_{DI} - A_{DV} and the output of comparator C_D accessible off-chip via separate pins.

A. Performance of Amplifier Blocks

Because of high package parasitics, it is possible to measure accurately only the DC and low frequency characteristics of the pinned out blocks. To validate the accuracy of the controller IC over process variations, the above measurements are conducted for 39 parts in the production lot. The measured net DC gains $g_{mi}R_S$ and $g_{mv}R_S$ (Fig. 9(a)), accounting for the gains of amplifiers A_{DI} , A_{DV} , and A_{DS} , vary by less than 6% around their mean values of 7.4V/A and 37.2V/V respectively. The net offset voltage (Fig. 9(b)) referred to the input of amplifier A_{DV} (including the effect of A_{DS}) is higher than that for A_{DI} because of the additional mismatch in the tail currents biasing the input differential pair of A_{DV} . Nonetheless, the standard deviation (σ) for net input offset voltages of both A_{DI} and A_{DV} remains low (0.86mV and 2.01mV respectively). The simulated 3dB frequencies (due to parasitic poles) at the worst-case corners for amplifiers A_{DI} , A_{DV} , and A_{DS} are 12MHz, 5MHz, and 13MHz respectively, with typical values roughly 40% higher.

B. Performance of $\Sigma\Delta$ Boost Converter

In assembling the system, the gate signal from the controller IC is buffered by an off-chip gate driver to drive the power switches. Various system performance parameters including stability, line/load regulation, power efficiency, and switching frequency variations are studied for a wide range of filter LC values. The results are discussed in the following text.

1) *Steady-State*: Steady-state inductor current and output voltage waveforms at $V_{IN}=2.7V$, $V_O=5V$, $L=22\mu H$, $C\approx 62\mu F$, $I_O=0.8A$, (Fig. 10) show ripples in the output voltage (40mV

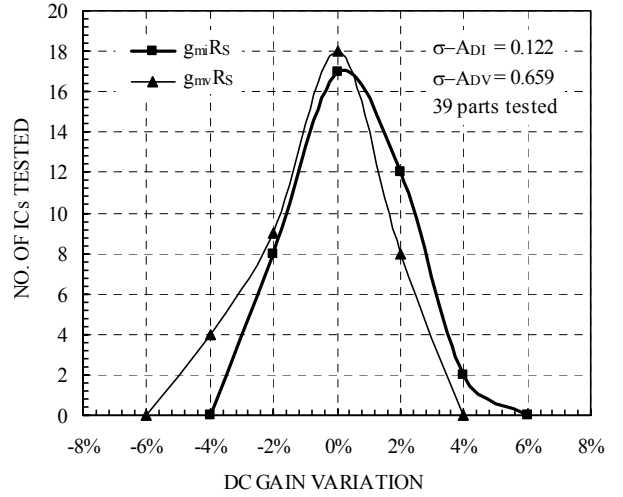


Fig. 9(a). Net DC gains K_I and K_V for the current and voltage loops.

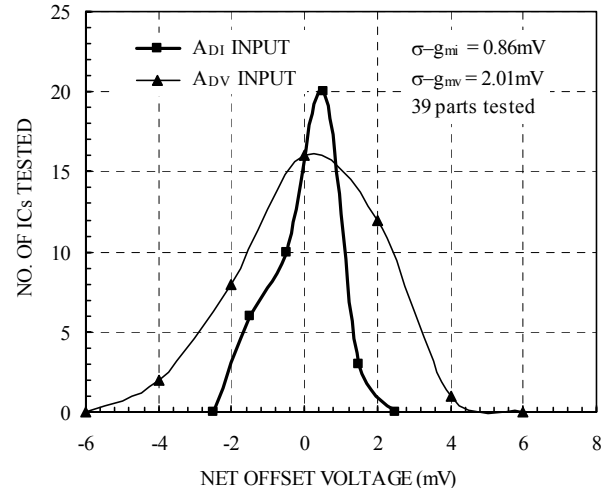


Fig. 9(b). Effective input offset voltages for Q_I and Q_V .

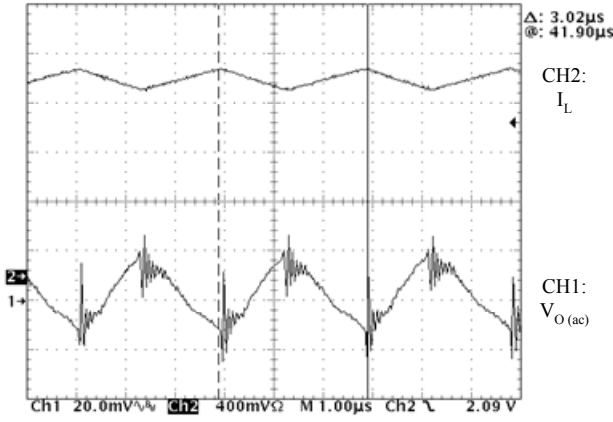


Fig. 10. Steady-state inductor current and output voltage waveforms.

pk-pk) and inductor current (190mA pk-pk), which are sensed by the $\Sigma\Delta$ controller through sensing ratios of 0.24V/V and ($A_{D1}R_1$) 0.4V/A respectively. The effective hysteresis window is roughly 650mVpk-pk and at the switching frequency of 330kHz, the value of $g_{mi}R_S R_1$ (from Table 1) is approximately 3.8V/A, which corresponds to a current ripple of 170mA pk-pk. The slight discrepancy between the measured and hand-calculated values is attributed to additional switching delays.

2) *Stability*: The unity-gain frequency of the voltage loop approaches that of the current loop for increasing filter

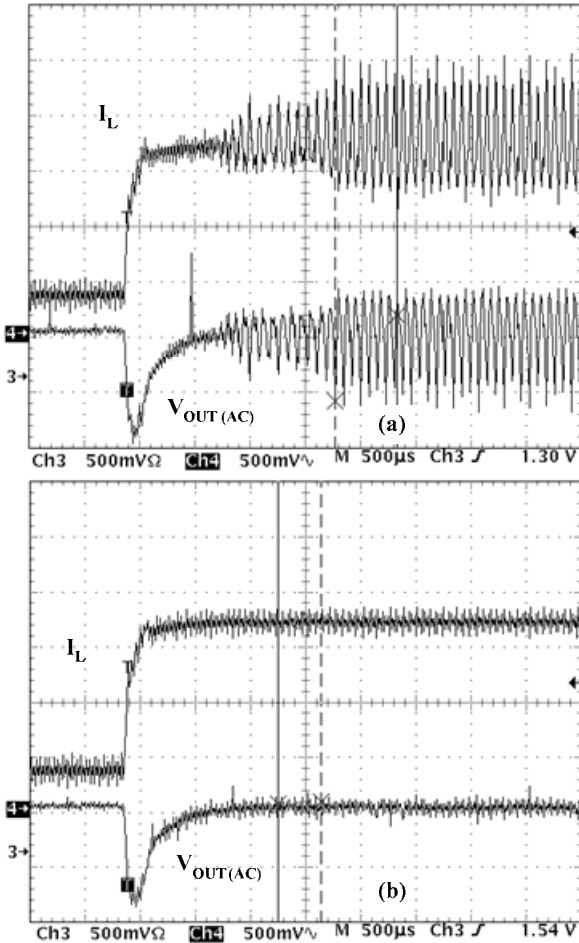


Fig. 11. Load step (0.3 to 0.8A) response for stability evaluation of the proposed controller at 30μH, showing (a) unstable operation at $C=14\mu\text{F}$ and (b) stable operation at $C=15\mu\text{F}$.

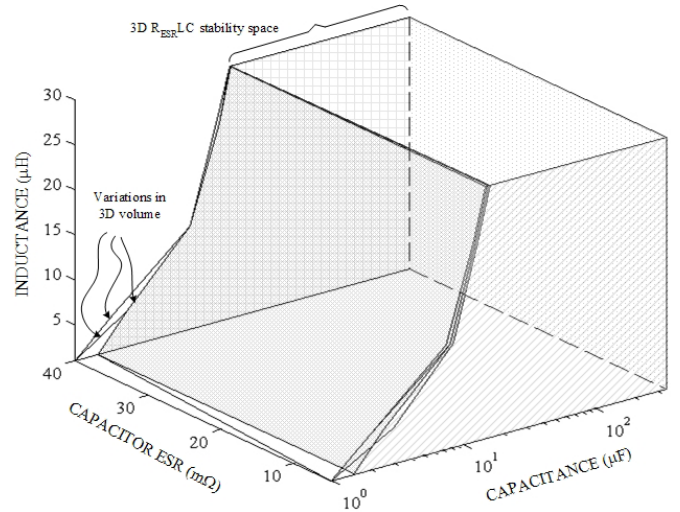


Fig. 12. Experimental 3-D R_{ESRLC} stability space for the evaluated $\Sigma\Delta$ controller across process variations (10 parts tested).

inductor and decreasing output capacitor values, destabilizing the $\Sigma\Delta$ operation, as seen from equation (10). In the evaluated circuit, the worst-case LC operation limits were determined in terms of the minimum capacitor value for a given inductor value at the maximum rated load (0.8A) and minimum supply voltage (2.7V) (equation (10)). Therefore, for a set value of the filter inductor, the capacitor value was gradually decreased (in steps of $0.5\mu\text{F}$) and the converter subjected to a load step of 0.3 to 0.8 A for each capacitor value, until the circuit became unstable with the inductor current and the output voltage showing persistent oscillations (Fig. 11).

In the other direction, the highest capacitor value was restricted to $350\mu\text{F}$ as a practical limit in portable applications. A similar procedure was followed for R_{ESR} , which was limited to $50\text{m}\Omega$ from ripple considerations in the output voltage. Given these constraints, the stable operating region of the $\Sigma\Delta$ controller can be represented as the enclosure of the R_{ESRLC} stability space (Fig. 12). As suggested by equation (10), the minimum capacitance for stable operation decreases – in this case from $15\mu\text{F}$ to $1\mu\text{F}$ as the inductor decreases from $30\mu\text{H}$ to $1\mu\text{H}$. Resistance R_{ESR} has little effect on the stability since the loop response near its unity-gain (switching) frequency is determined largely by the current loop (Fig. 2). The robustness of the controller design against process variations is confirmed by the nearly overlapping stability volumes measured for 10 samples from the production lot.

3) Switching Frequency Variations:

As explained in section II(B)(3), switching frequency with a constant gain $g_{mi}R_S$ would be ideally expected to decrease significantly as the input voltage changed from 2.7V to 4.2V, even including the effects of a constant switching delay and line regulation. This is illustrated in the constant $g_{mi}R_S$ curve for $5\mu\text{H}$ and 0.5A (Fig. 13), which shows a net switching frequency variation of 43%. In comparison, the measured curve has improved performance with the switching frequency variations restricted to 25% at 0.5A because of the inverse frequency dependence of gain $g_{mi}Z_S$ (Figs. 3 and 8). Fig. 13 also shows that as the load increases, the resulting droop in

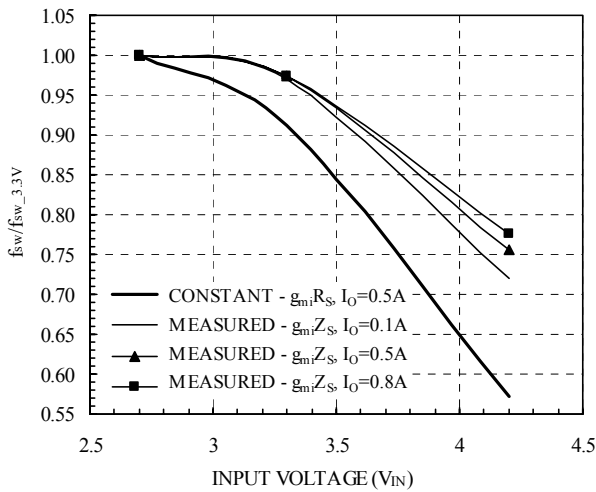


Fig. 13. Measured variation of switching frequency with input voltage at $5\mu\text{H}$ inductance.

output voltage increases the switching frequency further reducing its line variation at high loads.

4) *Line and Load Regulation*: Switching delays in the converter and finite loop-gain result in a variation of the DC output voltage from its desired value with changes in the supply voltage and load current. As the input voltage changes from 2.7V to 4.2V making the duty-cycle more asymmetrical, experimental results show that the error in the regulated output voltage becomes more negative, validating equation (14). Therefore, with the output voltage centered at a 3.3V input, the error voltage changes polarity as the input voltage transitions between its extreme values (Fig. 14). The increase in the error voltage magnitude with decreasing filter inductance expressly shows the effects of loop delays on the regulation performance. In the prototype IC, higher package parasitics (DIP40 package) and off-chip gate-drivers lead to a rise in switching delays whose effects were most evident at the lowest inductance value of $1\mu\text{H}$ (voltage error $\approx +1\%$, -2%). The steady-state error remains below $\pm 1\%$ at higher inductors that suppress the effects of switching delays. A package with lower parasitics would further improve the performance.

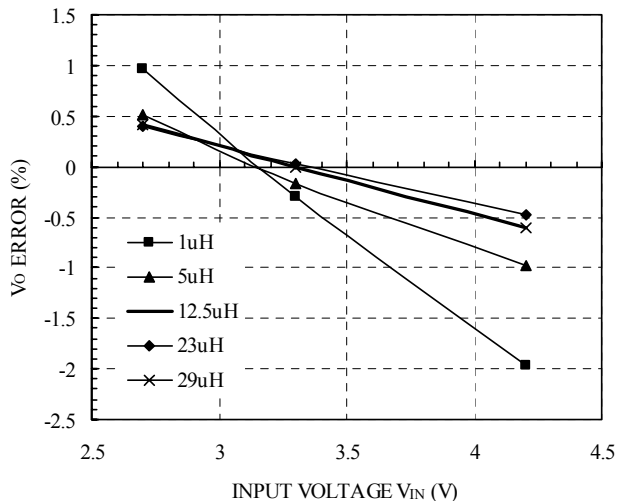


Fig. 14. Variation of output voltage with input voltage V_{IN} .

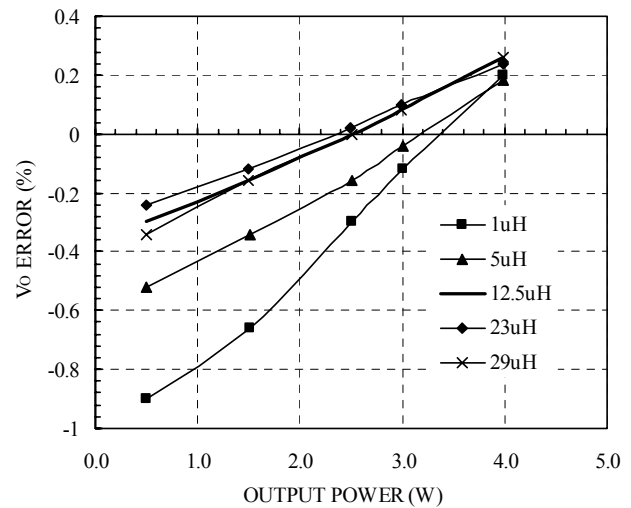


Fig. 15. Variation of output voltage with load current I_O .

Since the loop response near and at the switching frequency is dominated by the current loop, load variations do not affect the output voltage (Fig. 15) as significantly as line voltage variations. The effect of varying filter inductance remains the same as before with worst-case error ($+0.2\%$, -0.9%) at $1\mu\text{H}$.

5) *Efficiency*: Power efficiency in a variable filter, self-oscillating $\Sigma\Delta$ converter is subjected to several loss mechanisms and the dominance of one over the others is determined by not only line voltage and load, but also by filter inductance. Measured efficiency curves at a V_{IN} of 3.3V (Fig. 16) show that at high inductor values the efficiencies are higher at low load currents (91% at 0.1A, $29\mu\text{H}$, 120kHz) because of low switching frequencies and consequently low switching losses. However, at increased loads, higher inductors, which have a higher equivalent series resistance (ESR_L) due more coil turns, suffer from greater conduction losses leading to a reduced system efficiency (83% at 0.8A, $29\mu\text{H}$). This trend is reversed as the inductor value decreases because an increase in the switching frequency degrades low load efficiency (88% at 0.1A, $12.5\mu\text{H}$, 250kHz) and a reduced ESR_L increases high load efficiency (86.5% at 0.8A, $29\mu\text{H}$).

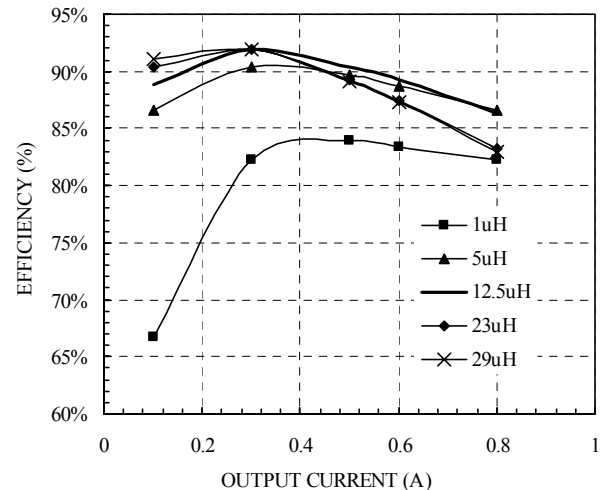


Fig. 16. Measured efficiency at 3.3V V_{IN} as a function of load current.

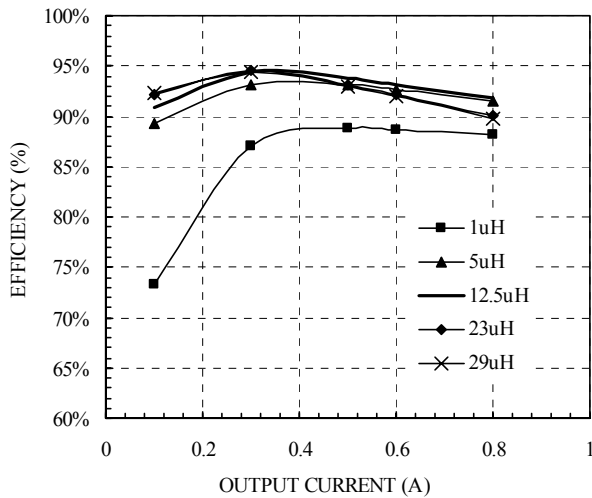


Fig. 17. Measured efficiency at 4.2V V_{IN} as a function of load current.

However, as the inductance decreases further, increase in the switching frequency is limited not by the comparator hysteresis but by the switching delays due to package parasitics. Therefore, the inductor-current ripple sharply increases (from 0.75A pk-pk at 5 μ H to 2.2A pk-pk at 1 μ H) making the RMS ripple current related conduction losses dominant. As a result, the overall efficiency reduces both at high and low loads (67% at 0.1A, 1 μ H, 550kHz; 82% at 0.8A, 1 μ H).

At higher input voltages, the efficiencies increase primarily because of reduced inductor and switch currents. Nevertheless, the trend remains as before (Fig. 17) with the lowest efficiencies at 1 μ H. The peak system efficiency approaches 94% at 0.3A, 29 μ H, and 4.2V supply voltage.

5) *Load Transient Response*: As mentioned earlier, a $\Sigma\Delta$ controller designed for a variable LC system is expected to suffer from a non-optimal transient response, and the proposed design is no exception. Nevertheless, by appropriately sizing the output capacitor, the desired transient response can be achieved. The measured 0.3-0.8A load transient response of the system (at $L=5\mu$ H, $C=200\mu$ F, and $V_{IN}=4.2$ V) is included (Fig. 18) for completeness.

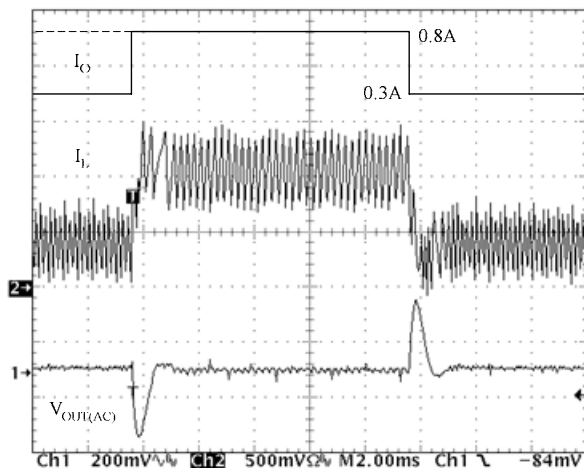


Fig. 18. 0.3A to 0.8A load step response at 5 μ H, 200 μ F, and $V_{IN} = 4.2$ V

V. CONCLUSION

A $\Sigma\Delta$ controller optimized for filter LC variations was presented, analyzed, and implemented (in a 0.6 μ m CMOS process) using simple low-gain, high-bandwidth, differential circuit blocks consisting essentially of source-degenerated input transconductance stages. Stable converter operation for orders of magnitude variations in filter LC and capacitor ESR values (1-30 μ H, 1-350 μ F, 5-50m Ω) was verified through experimental results. In designing the high speed $\Sigma\Delta$ controller, the use of low-gain blocks was validated by the open-loop DC gain accuracy ($\pm 6\%$ over process and line variations) and overall converter accuracy ($\pm 1.5\%$ over process, line, load, and filter variations). Although the system performance was somewhat degraded at low inductance values because of higher package parasitics, switching delays, and the consequent limitations on switching frequency, other performance metrics - efficiency (up to 95%) and switching frequency variations (improvement of 20%), were also well within specifications; a low-parasitic package would improve performance throughout the inductance range. Overall, with regard to the problem that an integrated boost dc-dc controller may be exposed to widely varying off-chip filter LC parameters jeopardizing stability and performance, the presented $\Sigma\Delta$ boost dc-dc controller gives a flexible, simple, and user-friendly solution.

VDD	2.7V - 4.2V
I _{bias}	0.6mA
Area	0.9mm ²
Peak converter efficiency	95%
R _{ESR} LC space	5-50m Ω 1-30 μ H 1-350 μ F
Feature size	0.6 μ m

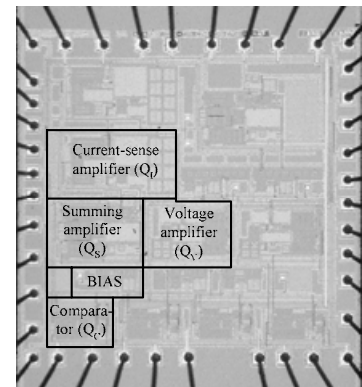


Fig. 19. Die photograph and key specifications of the fabricated $\Sigma\Delta$ controller IC.

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